

## List of Publications by Year in descending order

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#	Article	IF	CITATIONS
1	Comprehensive performance re-assessment of TFETs with a novel design by gate and source engineering from device/circuit perspective. , 2014, , .		40
2	20.2 A 57nW Software-Defined Always-On Wake-Up Chip for IoT Devices with Asynchronous Pipelined Event-Driven Architecture and Time-Shielding Level-Crossing ADC. , 2020, , .		24
3	The Challenges and Emerging Technologies for Low-Power Artificial Intelligence IoT Systems. IEEE Transactions on Circuits and Systems I: Regular Papers, 2021, 68, 4821-4834.	5.4	24
4	Challenges and Solutions of the TFET Circuit Design. IEEE Transactions on Circuits and Systems I: Regular Papers, 2020, 67, 4918-4931.	5.4	19
5	A 148-nW Reconfigurable Event-Driven Intelligent Wake-Up System for AloT Nodes Using an Asynchronous Pulse-Based Feature Extractor and a Convolutional Neural Network. IEEE Journal of Solid-State Circuits, 2021, 56, 3274-3288.	5.4	18
6	Ultra-Low-Power and Performance-Improved Logic Circuit Using Hybrid TFET-MOSFET Standard Cells Topologies and Optimized Digital Front-End Process. IEEE Transactions on Circuits and Systems I: Regular Papers, 2021, 68, 1160-1170.	5.4	12
7	A Software-Defined Always-On System With 57–75-nW Wake-Up Function Using Asynchronous Clock-Free Pipelined Event-Driven Architecture and Time-Shielding Level-Crossing ADC. IEEE Journal of Solid-State Circuits, 2021, 56, 2804-2816.	5.4	12
8	Benchmarking TFET from a circuit level perspective: Applications and guideline. , 2017, , .		11
9	Ultra-Low Power Hybrid TFET-MOSFET Topologies for Standard Logic Cells with Improved Comprehensive Performance. , 2019, , .		11
10	A 94.1 dB DR 4.1 nW/Hz Bandwidth/Power Scalable DTDSM for IoT Sensing Applications Based on Swing-Enhanced Floating Inverter Amplifiers. , 2021, , .		11
11	Energy-Efficient CMOS Humidity Sensors Using Adaptive Range-Shift Zoom CDC and Power-Aware Floating Inverter Amplifier Array. IEEE Journal of Solid-State Circuits, 2021, 56, 3560-3572.	5.4	11
12	Combinational Access Tunnel FET SRAM for Ultra-Low Power Applications. , 2018, , .		10
13	A 4-μW Bandwidth/Power Scalable Delta–Sigma Modulator Based on Swing-Enhanced Floating Inverter Amplifiers. IEEE Journal of Solid-State Circuits, 2022, 57, 709-718.	5.4	9
14	2.4-GHz 16-QAM Passive Backscatter Transmitter for Wireless Self-Power Chips in IoT. , 2020, , .		4
15	Re-Assessment of Steep-Slope Device Design From a Circuit-Level Perspective Using Novel Evaluation Criteria and Model-Less Method. IEEE Transactions on Circuits and Systems I: Regular Papers, 2021, 68,	5.4	1